OSRAM PL 520B **Datasheet**

Discontinued





Metal Can® TO38

PL 520B

Green Laser Diode in TO38 ICut Package











Applications

- Measurement Levelling
- Projection Home LED & Laser

- Projection Professional LED & Laser
- Stage Lighting (LED & Laser)

Features

- Optical output power (continuous wave): 80 mW ($T_c = 25$ °C)
- Typical emission wavelength: 520 nm
- Efficient radiation source for cw and pulsed operation
- Single mode semiconductor laser
- High modulation bandwidth
- Miniaturized TO38 ICut package
- Laser diode isolated against package



Ordering Information

Type Peak output power Ordering Code

typ. P_{opt}

PL520B 80 mW Q65111A7290

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Maximum Ratings 1)			
Parameter	Symbol		Values
Operating temperature	T_{op}	min.	-20 °C
	op.	max.	60 °C
Storage temperature	T _{stg}	min.	-40 °C
		max.	85 °C
Junction temperature	T_{j}	max.	120 °C
Peak output power 2)	P_{opt}	max.	100 mW
Forward current 3)	I _F	max.	300 mA
Reverse voltage 4)	V_{R}	max.	2 V
Soldering temperature	T_{s}	max.	260 °C
t _{max} = 10 sec			

Operation outside these conditions may damage the device. Operation at maximum ratings may influence lifetime.

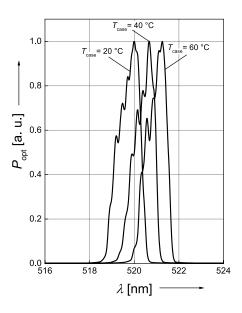
Characteristics

 P_{opt} = 80 mW; T_{case} = 25 °C

Parameter	Symbol		Values
Operating current 3)	l _{op}	typ. max.	200 mA 240 mA
Peak wavelength 5)	$\lambda_{ m peak}$	min. typ. max.	515 nm 520 nm 530 nm
Spectral bandwidth (FWHM)	$\Delta \lambda$	typ.	1 nm
Beam divergence (FWHM) parallel to pn-junction	$\Theta_{_{\parallel}}$	min. typ. max.	5 ° 6.3 ° 7.5 °
Beam divergence (FWHM) perpendicular to pn-junction	$\Theta_{\!\scriptscriptstyle \perp}$	min. typ. max.	18 ° 22.5 ° 25 °
Threshold current	I _{th}	typ. max.	40 mA 70 mA
Forward voltage 6)7)	V_{F}	typ. max.	6 V 8 V
TE polarization	P _{TE}	typ.	100:1
Modulation frequency	f	min.	100 MHz
Thermal resistance junction case real	R_{thJC}	typ.	38 K / W

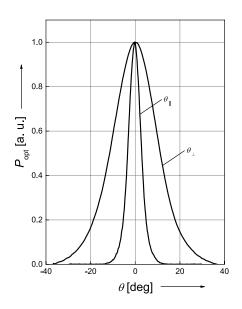
Relative Spectral Emission 8)

 $P_{opt} = f(\lambda)$



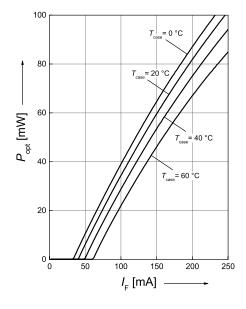
Beam Divergence 8)

 $P_{opt} = f(\Theta); T_{case} = 25 °C$



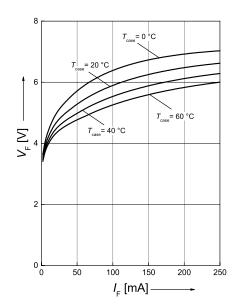
Optical Output Power 8)

 $P_{opt} = f(I_F)$



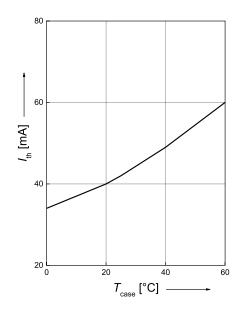
Opt. Power / Forward Voltage 8)

 $V_F = f(I_F)$



Threshold Current 8)

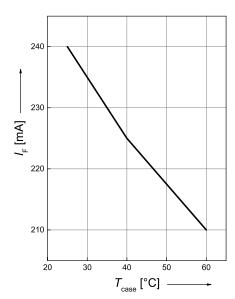
 $I_{th} = f(T_{C})$



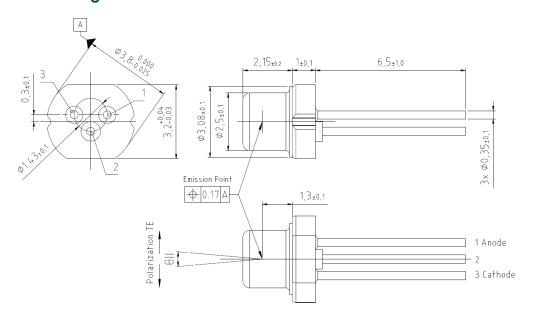


Max. Permissible Forward Current 8)

$$I_F = f(T_{case})$$



Dimensional Drawing 9)



C63062-A4180-A1 -03

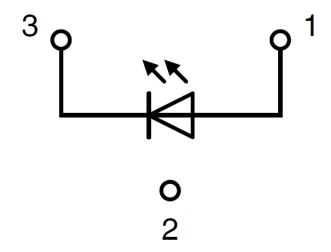
Further Information:

Approximate Weight: 310.0 mg

ESD advice: ATTENTION - Observe Precautions For Handling - Electrostatic Sensitive

Device

Electrical Internal Circuit



Pin	Description	
PIN 1	LD Anode	
PIN 2	Case	
PIN 3	LD Cathode	

Notes

Depending on the mode of operation, these devices emit highly concentrated visible and non visible light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

Important notes of operation for laser diode

a) Electrical operation

OSRAMs laser diodes are designed for maximum performance and reliability. Operating the laser diode above the maximum rating even for very short periods of time can damage the laser diode or reduce its lifetime. The laser diode must be operated with a suitable power supply with minimized electrical noise. The laser diode is very sensitive to electrostatic discharge (ESD). Proper precautions must be taken.

b) Mounting instructions

In order to maintain the lifetime of the laser diode proper heat management is essential. Due to the design of the laser diode heat is dissipated only through the base plate of the diode's body. A proper heat conducting interconnection between the diodes base plate and the heat sink must be maintained.



Notes

For further application related information please visit www.osram-os.com/appnotes

Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.

Glossary

- 1) Output power: The operation at the maximum ratings influences the life time.
- 2) **Brightness:** The brightness values are measured with a tolerance of ±11%.
- 3) Operating/Forward current: IF is measured with an internal reproducibility of ±7 % (acc. to GUM with a coverage factor of k = 3).
- Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any reverse bias shall be avoided.
- 5) Wavelength: λpeak is measured with an internal reproducibility of ±0.3 nm (acc. to GUM with a coverage factor of k = 3).
- 6) Operating/Forward voltage: VF is measured with an internal reproducibility of ±0.05 V (acc. to GUM with a coverage factor of k = 3).
- 7) Forward Voltage: The forward voltages are measured with a tolerance of ±0.1 V.
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.

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Revision History		
Version	Date	Change
1.0	2019-03-18	Initial Version
1.1	2019-04-12	Electro - Optical Characteristics (Diagrams)
1.2	2019-07-22	Discontinued
1.3	2022-04-01	Maximum Ratings New Layout Discontinued

Discontinued



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